

TVS DIODE 5.5VWM 19VC X3DFN2

Manufacturers	<u>ON Semiconductor, LLC</u>
Package/Case	X3DFN-2
Product Type	Circuit Protection
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for ESD8011MUT5G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

RFQ

General Description

The ESD8011 ESD protection diodes are designed to protect high speed data lines from ESD. Ultra-low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines.

Features

Ultra Low Capacitance (0.10 pF Typ, I/O to GND)

Protection for the Following IEC Standards: IEC 61000-4-2 (Level 4)

Low ESD Clamping Voltage

These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

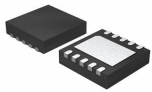
Application

ONSEMI



Related Products

[SZESD7016MUTAG](#)



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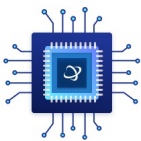
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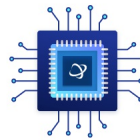
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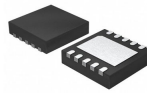
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